

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE01P18K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications. It is ESD protested.

General Features

● V_{DS} =-100V,I_D =-18A

 $R_{DS(ON)}\,{<}100m\Omega\;\textcircled{0}\;V_{GS}{=}{-}10V\quad(Typ:85m\Omega)$

 $R_{DS(ON)}$ <120m Ω @ V_{GS} =-10V (Typ:95m Ω)

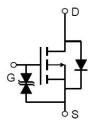
- Super high dense cell design
- Advanced trench process technology
- Reliable and rugged
- High density cell design for ultra low On-Resistance

Application

- Power management in notebook computer
- Portable equipment and battery powered systems

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-263-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE01P18D	NCE01P18D	TO-263-2L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	-100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	-18	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	-12	А
Pulsed Drain Current	I _{DM}	-72	А
Single pulse avalanche energy (Note 5)	E _{AS}	170	mJ
Maximum Power Dissipation	P _D	70	W
Derating factor		0.56	W/℃
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$ C

Thermal Characteristic

Thermal Resistance,Junction-to-Case (Note 2)	R _{θJc}	2.14	°C/W
Thermal Resistance,Junction-to-Ambient (Note 2)	$R_{\theta JA}$	60	°C/W



Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	-	,	'			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-100	-	-	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-100V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±20	μA
On Characteristics (Note 3)	-	,				•
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =-250μA	-1	-1.9	-3	V
Dunin Course On Otata Desiratore	-	V _{GS} =-10V, I _D =-16A	-	85	100	0
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-16A		95	120	mΩ
Gate resistance	R _G	F=1.0MHz	-	4.5	-	Ω
Forward Transconductance	G FS	V _{DS} =-50V,I _D =-10A	5	-	-	S
Dynamic Characteristics (Note4)	-	,	•			
Input Capacitance	C _{lss})/ 50//)/ 0)/	-	3810	-	PF
Output Capacitance	Coss	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	-	PF		
Reverse Transfer Capacitance	C _{rss}	F=1.0MHZ	-	94	-	PF
Switching Characteristics (Note 4)	-					
Turn-on Delay Time	t _{d(on)}		-	16	-	nS
Turn-on Rise Time	tr	V _{DD} =-50V,I _D =-16A	-	73	-	nS
Turn-Off Delay Time	$t_{\sf d(off)}$	V_{GS} =-10V, R_{GEN} =9.1 Ω	-	34	-	nS
Turn-Off Fall Time	t _f		-	57	-	nS
Total Gate Charge	Qg)/ 50\/\ 10A	-	70	-	nC
Gate-Source Charge	Q _{gs}	F=1.0MHz - V _{DD} =-50V,I _D =-16A - V _{GS} =-10V,R _{GEN} =9.1Ω -	-	12.5	-	nC
Gate-Drain Charge	Q _{gd}		-	15.5	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-10A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is	-	-	-	-18	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =-16A	-	88.3	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	65.9	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negl	igible (turi	n-on is do	minated b	y LS+LD)

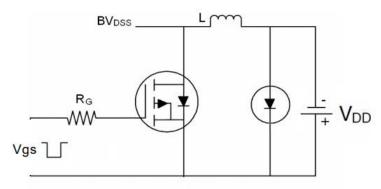
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width $\leq 300 \mu s$, Duty Cycle $\leq 2\%$.
- 4. Guaranteed by design, not subject to production

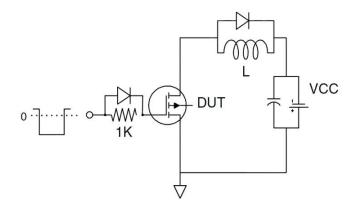


Test Circuit

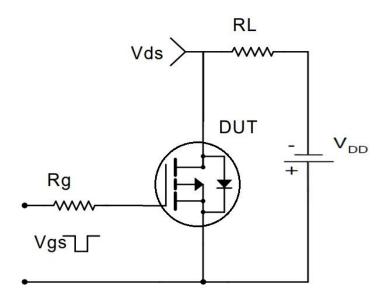
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

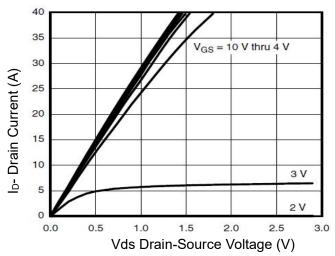


Figure 1 Output Characteristics

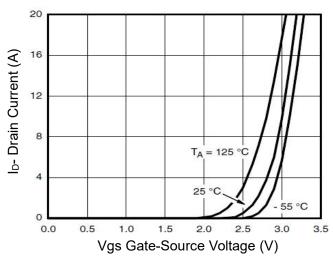


Figure 2 Transfer Characteristics

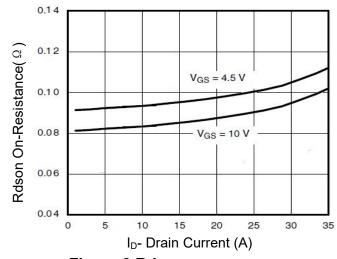


Figure 3 Rdson- Drain Current

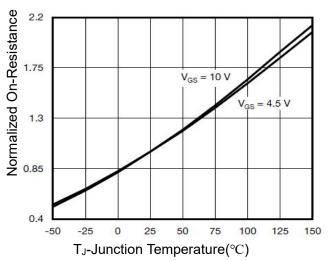


Figure 4 Rdson-JunctionTemperature

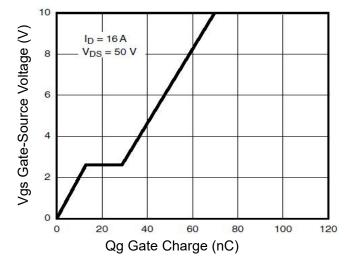


Figure 5 Gate Charge

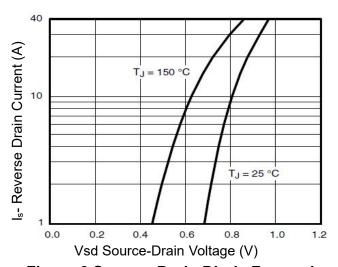
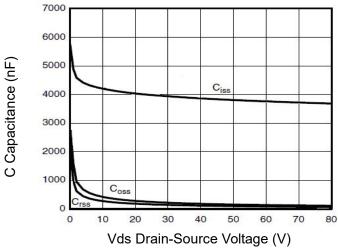


Figure 6 Source- Drain Diode Forward





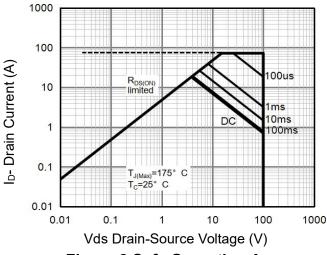
(A) To Drain Current (B) To Dr

20

Figure 7 Capacitance vs Vds

Figure 9 Drain Current vs Case Temperature

T_C Case Temperature(°C)



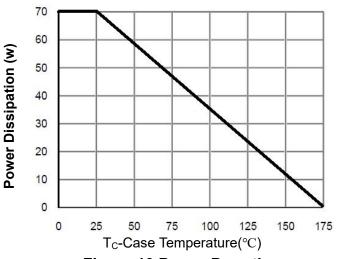


Figure 8 Safe Operation Area

Figure 10 Power De-rating

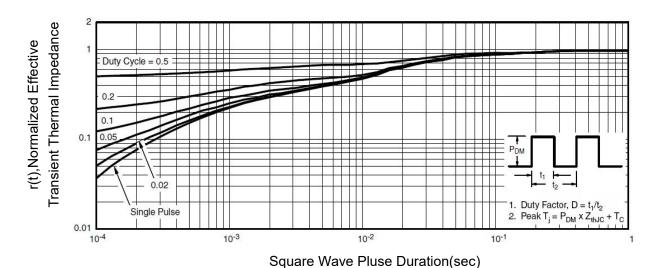
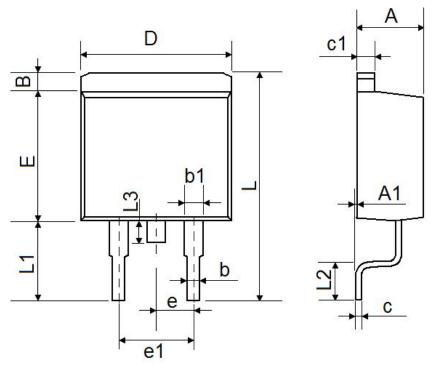
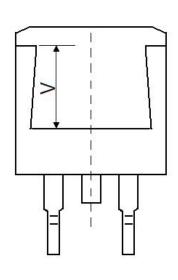


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-263-2L Package Information





Cumahad	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	4.470	4.670	0.176	0.184	
A1	0.000	0.150	0.000	0.006	
В	1.170	1.370	0.046	0.054	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.310	0.530	0.012	0.021	
c1	1.170	1.370	0.046	0.054	
D	10.010	10.310	0.394	0.406	
E	8.500	8.900	0.335	0.350	
е	2.540	TYP.	0.100	TYP.	
e1	4.980	5.180	0.196	0.204	
L	15.050	15.450	0.593	0.608	
L1	5.080	5.480	0.200	0.216	
L2	2.340	2.740	0.092	0.108	
L3	1.300	1.700	0.051	0.067	
V	5.600	REF	0.220 REF		



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